Depth Profile of the Hydrogenation of Multi Walls Carbon Nanotubes with Soft-to-Hard X-ray Photoemission Spectroscopy

Ptolemy Collaboration Meeting, July 1-2, 2025

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Aligned Nanotube Detector for Research On MeV Darkmatter





Possible Tritiated Target Solutions

Tritium in a solid-state target



Nano-porous graphene





Two Samples and a Plasma Recipe for Hydrogenation



Two samples from the same batch Annealing 650 °C

CNT pristine

Annealing Used as a reference









CNT plasma H

Exposed to hydrogen plasma:

- **0** 100 W
- **O** 0.7 mbar H_2 , 300 sccm
- **0**1h

Kept in low vacuum during transfer

Annealing at T < 300 °C





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diamond



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Photoemission Fingerprints of Highly Hydrogenated CNTs



Monochromatized AI K α = 1487.6 eV

• Hydrogenation causes **sp²** to **sp³** transitions

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o 0.5 eV lower Work function in H-CNT

$I_{sp3} / (I_{sp2} + I_{sp3}) = 0.67$

XPS

O sp²-to-sp³ carbon hybridization





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Electron Energy Loss Confirms Hydrogenation





Ο π plasmon quenching

O Band Gap opening

EELS

 $E_{primary} = 90 \text{ eV}$

O C-H stretching





Electron Energy Loss Confirms Hydrogenation



EELS

 $E_{primary} = 90 \text{ eV}$

Ο π plasmon quenching

O Band Gap opening



Surface sensitive techniques!



How Deep Does the Hydrogenation Go?

• Lineshape changes provide insight into sp² vs sp³ carbon hybridization



O Variable photon energy allows probing from surface to inner layers



Not surface-limited, not fully bulk...





Inelastic Mean Free Path

$h\nu$ (keV)	$\lambda_{graphite} \ (nm)$
350	0.5
800	1.0
1400	2.0
4000	4.7
8000	9.1

- Line shape differences between CNT and H-CNT decrease with depth sensitivity
- With 8 keV photon there is still a sign of hydrogenation



Not surface-limited, not fully bulk... but more H than in nano-porous graphene ¹⁰











Quantifying the Sp³ Content with Soft Photons



 $\frac{I_{sp^3}}{I_{sp^3} + I_{sp^2}} = 0.74$

 $\frac{I_{sp^3}}{I_{sp^3} + I_{sp^2}} = 0.61$



Lineshape Changes due to Recoil Effects in HAXPES



FIG. 1. Carbon 1s photoelectron spectra of CF_4 , measured at different photon energies: (a) 330 eV, (b) 2.3 keV, (c) 3.0 keV, (d) 6.9 keV, and (e) 8.5 keV. Dots, experimental data points; continuous red line, least-squares curve-fitting result; vertical sticks, positions and relative intensities of the vibrational peaks.

gaseous molecule

Kukk et al., Phys. Rev. Lett. 121, 073002 (2018)

FIG. 1. (Color online) (a) Photon energy dependence of C 1s core-level spectra of graphite. The soft x ray ($h\nu$ =340 and 870 eV) and hard x ray ($h\nu$ =5950 and 7940 eV) are measured at the emission angles of 90° and 85° relative to the sample surface. (b) Theoretically obtained spectra taking into account the recoil effect in a Debye model with $\hbar \omega_{b,D} = 75$ meV.

Takata et al., Phys. Rev. B 75, 233404 (2007)



Hit Me (Photon) One More Time

pristine CNT



$$E_r = \frac{m_e}{M} E_k \qquad \frac{m_e}{M_C} \sim 4.6 \times 10^{-5}$$

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Measured energy shift wrt hv = 800 eV

O 4000 eV: ~ 100 meV

O 8000 eV: ~ 300 meV

Free Atom Recoil

hv 800 eV hv 4 KeV hv 8 KeV

 $E_r \sim 0.02 \text{ eV}$ $E_r \sim 0.17 \text{ eV}$ $E_r \sim 0.37 \text{ eV}$



Bending vs Stretching Modes Angular Dependence

Graphite

Grazing emission: in plane stretching mode, broader peak

Normal emission: out-of-plane bending mode









C Highly hydrogenated CNTs with minimal oxygen contamination

UNIX HYDROGENATION INVOLVES MAINLY THE OUTER LAYERS, BUT IS NOT LIMITED TO THE VERY SURFACE

Can we quantify hydrogen distribution in depth?

Solution Recoil effects observed in pristine CNTs, average energy shift consistent with graphite

How can we explain the angular dependence? What about H-CNTs? Can we study C-H vibrations?

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Update on Tritiation feasibility

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We have started measurements of the residual gas composition during hydrogenation (deuteration)

Check for (heavy) water and light hydrocarbons as secondary products

Stay tuned!



Hydrogen Plasma vs Thermal Cracking Hydrogenation



$I_{sp3} / (I_{sp2} + I_{sp3}) \approx 67\%$ WF = 3.81 ± 0.05 eV



Atomic Deuterium bonding to Multi-Walled Carbon Nano Tubes

Sammar Tayyab et al., to be published

$$I_{sp3} / (I_{sp2} + I_{sp3}) \approx 70\%$$

WF = 3.84 ± 0.05 eV







Hit Me (Photon) One More Time



- 800 eV ~ 1400 eV no major C-C recoil effect
- 4000 eV energy shift ~ 100 meV
- 8000 eV energy shift ~ 250 meV

 Mix of depth inhomogeniusness and recoil effect hard to disentangle

Sp3 lower at higher information depth, effective sharper line shape and shift to lower BE

Recoil increase with photon energy, peak shift to lower KE, higher BE



1 ug Tritium

assumptions

- Layer separation as in graphite = 0.35 nm
- Electron mean free path equals to IMFP as in graphite

 $\frac{sp3}{sp3 + sp2} = \text{H:C stoichiometry}$

• Exponential decaying hydrogen distribution in depth

 $1 \text{ ug } m_{H^3} = 0.33 \text{ ug } m_H = \approx 10$

Characteristic penetration depth: 8.5 layers $m_H \approx 57 \, \mathrm{ng/cm}^2$





* 5 cm² total







Uniform overlayer sp3 over substrate sp2

(c) Semi-infinite substrate with uniform overlayer of thickness t— Peak k from substrate with $E_{kln} \equiv E_k$: $N_k(\theta) = I_0 \Omega_0(E_k) A_0(E_k) D_0(E_k) \rho \, \mathrm{d}\sigma_k / \mathrm{d}\Omega \, \Lambda_e(E_k)$ $\times \exp\left(-t/\Lambda_{\rm e}'(E_k)\sin\theta\right)$ Peak *l* from overlayer with $E_{kln} \equiv E_l$: $N_l(\theta) = I_0 \Omega_0(E_l) A_0(E_l) D_0(E_l) \rho' \, \mathrm{d}\sigma_l / \mathrm{d}\Omega \, \Lambda_e'(E_l)$ $\times [1 - \exp(-t/\Lambda_e'(E_l) \sin \theta)]$

where

 $\Lambda_{e}(E_{k})$ = an attenuation length in the substrate $\Lambda_{e}'(E_k) = an$ attenuation length in the overlayer $\rho = an$ atomic density in the substrate ρ' = an atomic density in the overlayer.

$$\frac{I_{sp3}}{I_{sp3} + I_{sp2}} = \frac{I_{\text{overlayer}}}{I_{\text{overlayer}} + I_{\text{substrate}}} = \frac{1 - e^{-d/\lambda \cos \theta}}{1 - e^{-d/\lambda \cos \theta} + e^{-d/\lambda \cos \theta}} = 1 - e^{-d/\lambda}$$

- (117)
- (118)

Uniform overlayer model does not work well for both 800 and 1400 photons

$$\lambda = 1nm, \frac{sp3}{sp3 + sp2} = 0.74$$

$\lambda = 2nm, \frac{sp3}{sp3 + sp2} = 0.61$

 $1 - e^{-d/2} = 0.61 \Rightarrow d = -2\ln(0.39) = 1.88$ nm

((1.88+1.35)/2=1.615

hv = 800 eV

$1 - e^{-d/1} = 0.74 \Rightarrow d = -\ln(0.26) = 1.35 \,\mathrm{nm}$

hv = 1400 eV

2*(1.88-1.35)/(1.88+1.35) =0.328



Exponential density of sp3 overlayer

 $f_{sp3}(z) = f_0 \cdot e^{-z/d_0}$

$$f_{sp2}(z) = 1 - f_{sp3}(z)$$

$$I_{sp3} \propto \int_0^\infty f_{sp3}(z) \cdot e^{-z/\lambda} dz = \int_0^\infty e^{-z/d_0} \cdot e^{-z/\lambda} dz = \int_0^\infty e^{-z(1/d_0 + 1/\lambda)} dz I_{sp3} \propto \frac{1}{(1/d_0 + 1/\lambda)} = \frac{d_0 \lambda}{d_0 + \lambda}$$

$$I_{sp2} \propto \int_0^\infty \left[1 - f_{sp3}(z) \right] \cdot e^{-z/\lambda} dz = \int_0^\infty \left(1 - e^{-z/d_0} \right) \cdot e^{-z/\lambda} dz = \lambda \left(1 - \frac{d_0}{d_0 + \lambda} \right) = \lambda \left(\frac{\lambda}{d_0 + \lambda} \right) = \frac{\lambda^2}{d_0 + \lambda}$$

sp³ is 100% at the surface d₀ characteristic sp³ length



Exponential density of sp3 overlayer is better

 $f_{sp3}(z) = f_0 \cdot e^{-z/d_0}$

$$f_{sp2}(z) = 1 - f_{sp3}(z)$$

$$\frac{I_{sp3}}{I_{sp3} + I_{sp2}} = \frac{d_0 \lambda / (d_0 + \lambda)}{d_0 \lambda / (d_0 + \lambda) + \lambda^2 / (d_0 + \lambda)} = \frac{d_0}{d_0 + \lambda}$$

hv = 800 eV

$$\lambda = 1nm, \frac{sp3}{sp3 + sp2} = 0.74$$

$$d_0 = \frac{0.74}{1 - 0.74} = 2.85 \,\mathrm{nm}$$

(3.13+2.85)/2=2.99

sp³ is 100% at the surface d₀ characteristic sp³ length

hv = 1400 eV

$$\lambda = 2nm, \frac{sp3}{sp3 + sp2} = 0.61$$

$$d_0 = \frac{0.61}{1 - 0.61} = 3.13 \,\mathrm{nm}$$

2*(3.13-2.85)/(3.13+2.85) =0.0936



Sp3 in equivalent layers of graphite

d = 1.61 (uniform model)

1.61/0.35 = 4.6

$d_0 = 2.99$ (exponential model)

2.99/0.35 = 8.5

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Layer separation in graphite = 0.35 nm



Hydrogen surface density uniform model a spanne

 $n_C \approx 3.82 \times 10^{13}$ atomi/mm²

 $m_H = 1.0078 \text{ u} = 1.0078 \cdot 1.6605 \times 10^{-24} \text{ g} \approx 1.6736 \times 10^{-24} \text{ g}$

$N_H = 4.6 \cdot n_C = 4.6 \cdot 3.82 \times 10^{13} = 1.7572 \times 10^{14} \text{ atomi H/mm}^2$

 $m_H \approx 29 \, \mathrm{ng/cm}^2$



Hydrogen surface density exponential model a spanne

$$n_0 = \frac{3.82 \times 10^{13}}{0.335} \approx 1.14 \times 10^{14} \text{ atomi/m}$$

$$N_{H} = \int_{0}^{\infty} n_{H}(z) \, dz = \int_{0}^{\infty} n_{0} \cdot e^{-z/d_{0}} dz = n_{0}$$

nm²/nm

$d_0 = 1.14 \times 10^{14} \cdot 3 = 3.42 \times 10^{14}$ atomi/mm²

$m_H \approx 57 \, \mathrm{ng/cm}^2$



1 ug Hydrogen (uniform model)





* 30 cm² in total



1 ug Hydrogen (exponential model)





* 15 cm² total



1 ug Tritium (exponential model)

Layer separation as in graphite = 0.35 nm Electron IMFP as in graphite

 $\frac{sp3}{sp3 + sp2} = \text{H:C stoichiometry}$

$1 \text{ ug } m_{H^3} = 0.33 \text{ ug } m_H = \approx 10$

Characteristic penetration depth: 8.5 layers $m_H \approx 57 \, \mathrm{ng/cm}^2$



* 5 cm² total



O1s and Fe 2p content

Cross section values

Yeh & Lindau (1985) Scofield (1973)





Beam makes hydrogen desorbs









Recoil Effects in Photoemission: Hit Me (Photon) One More Time

- Recoil: shift
- Kind/number of phonon excitations: asymmetric broadening



- 800 eV ~ 1400 eV no major C-C recoil effect
- 4000 eV energy shift ~ 100 meV 8000 eV energy shift ~ 250 meV

- prominent sp3 component gradually decreases with photon energy
- From 4000 eV to 8000 eV increasing recoil effect

- Modello semiclassico Armonico (no dissipaz)
- Single phonon
 - No coupling elettronico (curveDOI: 10 de log Rev B.75.233404 simmetriche no coda di drude)



Bending vs Stretching modes with High Energy ARPES



Out of plane (normal emission): higher recoil energy
È vero per la grafite ma per i nanotubi non dovrebbe essere l'op





XPS analysis: from sp² towards sp³



Counts (A.U.)







UPS: Work Function Changes and Band Gap Opening



Work Function measure:



BE (eV)



Hydrogenation Signatures in Energy Loss Spectroscopy

Electron Energy Loss Spectroscopy



- o CH stretching appears at ~ 0.36 eV
- and low energy losses

o Quenching of the **π plasmon**

o Wide band gap opening ~ 6.9 eV







